Product datasheet Characteristics

TM3DQ8T

module TM3 - 8 outputs transistor PNP



Main

Range of product	Modicon TM3	
Product or component type	Discrete output module	
Range compatibility	Modicon M221 Modicon M251 Modicon M241	
Discrete output type	Transistor	
Discrete output number	8	
Discrete output logic	Positive logic (source)	
Discrete output voltage	24 V DC for transistor output	
Discrete output current	50 mA for transistor output	

Complementary

Complementary		
Discrete I/O number	8	
Current consumption	5 mA at 5 V DC via bus connector at state off 0 mA at 24 V DC via bus connector at state off 20 mA at 24 V DC via bus connector at state on 10 mA at 5 V DC via bus connector at state on	
Response time	450 μs for turn-on 450 μs for turn-off	
Leakage current	0.1 mA for transistor output	
Voltage drop	0.4 V	
Tungsten load	3 W for transistor output	
Local signalling	Green for output status	
Electrical connection	Removable screw terminal block pitch 5.08 mm with 11 terminal(s) of 2.5 mm² connection capacity for outputs	
Cable length	<= 30 m unshielded cable for transistor output	
Insulation	500 V AC between output and internal logic Non-insulated between outputs	
Marking	CE	
Mounting support	Top hat type TH35-15 rail conforming to IEC 60715 Top hat type TH35-7.5 rail conforming to IEC 60715	

	Plate or panel with fixing kit	
Height	90 mm	
Depth	84.6 mm	
Width	27.4 mm	
Product weight	0.76 kg	

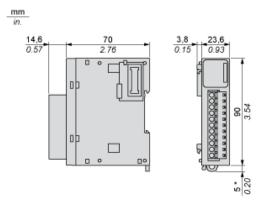
Environment

Standards	EN/IEC 61010-2-201 EN/IEC 61131-2
Product certifications	CULus C-Tick
Resistance to electrostatic discharge	4 kV (on contact) conforming to EN/IEC 61000-4-2 8 kV (in air) conforming to EN/IEC 61000-4-2
Resistance to electromagnetic fields	10 V/m at 80 MHz1 GHz conforming to EN/IEC 61000-4-3 3 V/m at 1.4 GHz2 GHz conforming to EN/IEC 61000-4-3 1 V/m at 2 GHz3 GHz conforming to EN/IEC 61000-4-3
Resistance to magnetic fields	30 A/m at 5060 Hz conforming to EN/IEC 61000-4-8
Resistance to fast transients	1 kV for I/O conforming to EN/IEC 61000-4-4
Surge withstand	1 kV for I/O (DC) in common mode conforming to EN/IEC 61000-4-5
Resistance to conducted disturbances, induced by radio frequency fields	10 Vrms at 0.1580 MHz conforming to EN/IEC 61000-4-6 3 Vrms at spot frequency (2, 3, 4, 6.2, 8.2, 12.6, 16.5, 18.8, 22, 25 MHz) conforming to Marine specification (LR, ABS, DNV, GL)
Electromagnetic emission	Radiated emissions, test level: 40 dBμV/m QP with class A, condition of test: 10 m (radio frequency: 30230 MHz) conforming to EN/IEC 55011 Radiated emissions, test level: 47 dBμV/m QP with class A, condition of test: 10 m (radio frequency: 230 MHz1 GHz) conforming to EN/IEC 55011
Ambient air temperature for operation	-1055 °C for horizontal installation -1035 °C for vertical installation
Ambient air temperature for storage	-2570 °C
Relative humidity	1095 % without condensation in operation 1095 % without condensation in storage
IP degree of protection	IP20 with protective cover in place
Pollution degree	2
Operating altitude	02000 m
Storage altitude	03000 m
Vibration resistance	3.5 mm (vibration frequency: 58.4 Hz) on DIN rail 3 gn (vibration frequency: 8.4150 Hz) on DIN rail 3.5 mm (vibration frequency: 58.4 Hz) on panel 3 gn (vibration frequency: 8.4150 Hz) on panel
Shock resistance	15 gn (test wave duration:11 ms)

Offer Sustainability

Green Premium product	
У	

Dimensions

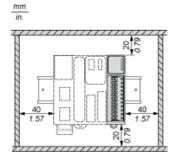


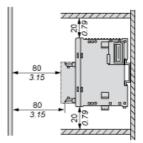
(*) 8.5 mm/0.33 in. when the clamp is pulled out.

Product datasheet Mounting and Clearance

TM3DQ8T

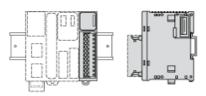
Spacing Requirements





TM3DQ8T

Mounting on a Rail



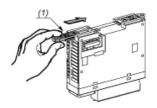
Incorrect Mounting



Product datasheet Mounting and Clearance

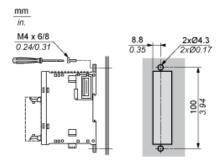
TM3DQ8T

Mounting on a Panel Surface



(1) Install a mounting strip

Mounting Hole Layout

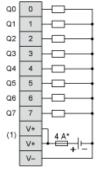


Product datasheet Connections and Schema

TM3DQ8T

Digital Transistor Output Module (8-channel, Source)

Wiring Diagram



- (*) Type T fuse
- (1) The V+ terminals are connected internally.